N-Channel 20V (D-S) Power MOSFET

Features

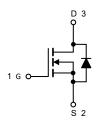
- 100% Avalanche Tested
- Halogen Free, Pb-Free
- RoHS Compliant



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Applications

- Relay driver
- Switching circuits
- High-side load switch
- High-speed line driver



Absolute Maximum Ratings (T _A =25°C unless otherwise noted)						
Parameter	Symbol	Value	Unit			
Drain Source Voltage	V _{DS}	20	V			
Gate Source Voltage	V_{GS}	±12	V			
Drain Current, Continuous V _{GS} =10V	T _C =25°C	l _D	3.3	А		
Drain Current, Pulsed (Note 1)	l _{DM}	11.4	Α			
Power Dissipation	T _C =25°C	P_D	1.1	W		
Operating Junction/ Storage Tempera	T _J / T _{STG}	-55 to +150	°C			

Note 1: Single pulse; $t_p \le 1$ us.

Thermal Characteristics							
Parameter	Symbol	Max	Unit				
Thermal Resistance Junction to Ambient (Note 2)	R _{thJA}	140	°C/W				

Note 2: Device mounted on 1 square inch FR4 PCB board, with 2oz single-sided copper, in a 25°C still air environment.



Electrical Characteristics (T _A =25°C unless otherwise noted)						
Parameter	neter Symbol Test Conditions		Min	Тур	Max	Unit
Drain Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V			1	uA
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _{DS} =250uA	0.4		1	V
Gate Leakage Current	Igss	V _{GS} =±12V			±100	nA
Drain-Source On-state Resistance (Note 3)		V _{GS} =4.5V, I _D =2A		22	30	mΩ
	R _{DS(on)}	V _{GS} =2.5V, I _D =1A		27	40	
Total Gate Charge	Qg			4		nC
Gate-Source Charge	Q _{gs}	V _{GS} =10V, V _{DS} =4.5V, I _D =3.6A		0.65		
Gate-Drain Charge	Q_{gd}			1.5		
Turn-on Delay Time	t _{d(on)}			7		
Turn-on Rise Time	t r	V _{GS} =4.5V, V _{DD} =20V,		10.4		
Turn-off Delay Time	t _{d(off)}	$R_G=3\Omega$, $R_L=10\Omega$		12.9		ns
Turn-off Fall Time	t _f			3.2		
Input Capacitance	Ciss			304		
Output Capacitance	Coss	V _{GS=} 0V, V _{DS} =20V, f=1MHz		46		pF
Reverse Transfer Capacitance	Crss			38		

Reverse Diode Characteristics (T _A =25°C unless otherwise noted)						
Parameter	Symbol	ymbol Test Conditions		Тур.	Max.	Unit
Forward Current, Continuous	Isp	T _C =25°C			3.3	Α
Diode Forward Voltage (Note 3)	V _{SD}	I _F =1A, V _{GS} =0V		0.7	1.2	V

Note 3: Pulse test; pulse width ≤ 380µs, duty cycle ≤ 1%.



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Typical Characteristics Curves (TA = 25°C unless otherwise noted)



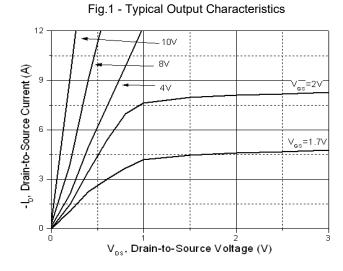


Fig.2 - V_{GS(th)} vs. Junction Temperature

0.70

0.65

0.60

0.55

0.40

0.30

T_J, Juntion Temperature(° C)

Fig.3 - Drain-to-Source Breakdown Voltage vs. Junction Temperature

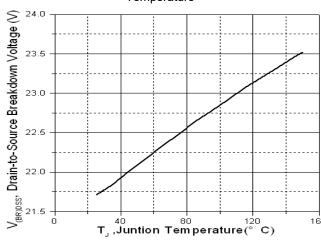
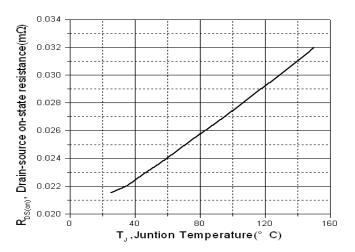
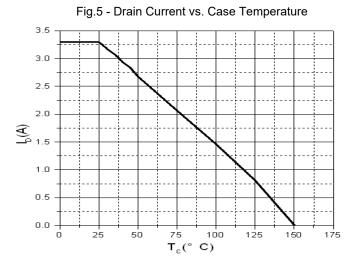
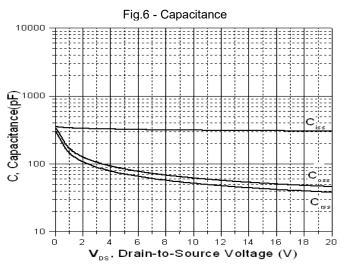


Fig.4 - R_{DS(on)} vs. Junction Temperature

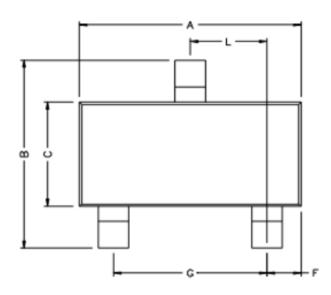


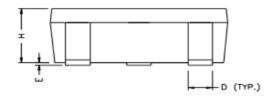


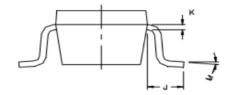


Package Outline Dimensions (Unit: millimeters)

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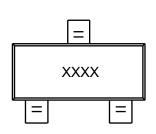




REF.	Milli	meter	REF.	Millimete		
KEF.	Min.	Max.	KEI.	Min.	Max.	
Α	2.80	3.00	G	1.80	2.00	
В	2.30	2.50	Н	0.90	1.1	
С	1.20	1.40	K	0.10	0.20	
D	0.30	0.50	7	0.35	0.70	
E	0	0.10	L	0.92	0.98	
F	0.45	0.55	М	0°	10°	



Marking Outline



Part Name: GMN2300UP

1. P/N Mark: 2300



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